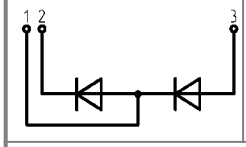
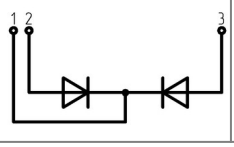
Electrically isolated base plate
Industrial standard package
Simplified mechanical design, rapid assembly
Pressure contact

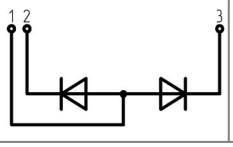
Double Diode Module For Phase Control MDx-400-52-A2

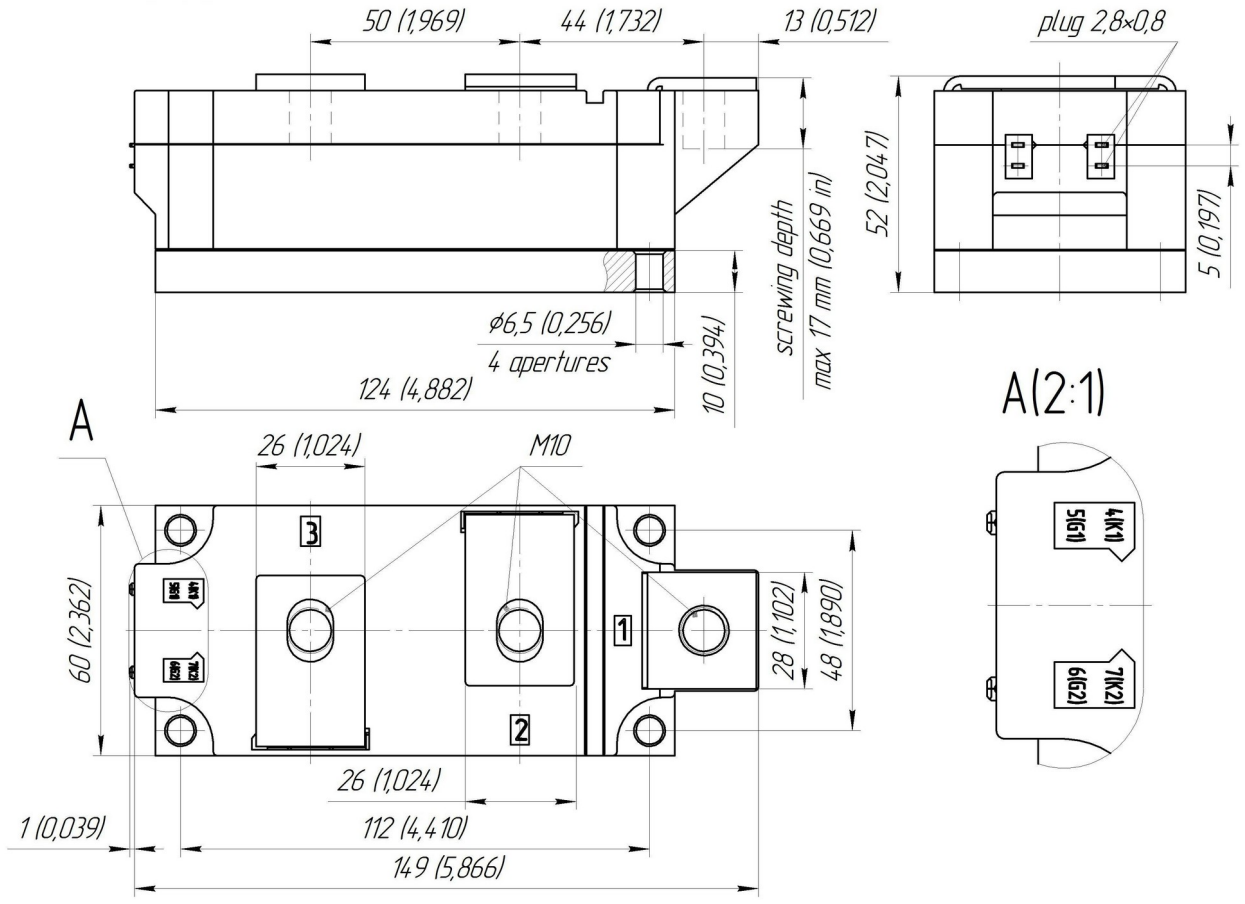
Average forward current		I_{FAV}	400 A	
Repetitive peak reverse voltage		V_{RRM}	4600 ÷ 5200 V	
V_{RRM}, V	4600	4800	5000	5200
Voltage code	46	48	50	52
T_j, °C	– 40 ÷ 140			

MD3 **MD4** **MD5**









All dimensions in millimeters (inches)

MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values	Test conditions	
ON-STATE					
I_{FAV}	Average forward current	A	400	T_c=97 °C; 180° half-sine wave; 50 Hz	
I_{FRMS}	RMS forward current	A	628		
I_{FSM}	Surge forward current	kA	8.0 9.0	T_j=$T_{j\,max}$ T_j=25 °C	180° half-sine wave; t_p=10 ms; single pulse; V_R=0 V;
			8.5 10.0	T_j=$T_{j\,max}$ T_j=25 °C	180° half-sine wave; t_p=8.3 ms; single pulse; V_R=0 V;
I^2t	Safety factor	$A^2s{\cdot}10^3$	320 400	T_j=$T_{j\,max}$ T_j=25 °C	180° half-sine wave; t_p=10 ms; single pulse; V_R=0 V;
			290 410	T_j=$T_{j\,max}$ T_j=25 °C	180° half-sine wave; t_p=8.3 ms; single pulse; V_R=0 V;
BLOCKING					
V_{RRM}	Repetitive peak reverse voltages	V	4600÷5200	$T_{j\,min}$< T_j <$T_{j\,max}$; 180° half-sine wave; 50 Hz;	
V_{RSM}	Non-repetitive peak reverse voltages	V	4700÷5300	$T_{j\,min}$< T_j <$T_{j\,max}$; 180° half-sine wave; single pulse;	
V_R	Reverse continuous voltages	V	0.6·V_{RRM}	T_j=$T_{j\,max}$;	
THERMAL					
T_{stg}	Storage temperature	°C	-40 ÷ 50		
T_j	Operating junction temperature	°C	-40 ÷ 140		
$T_{c\,op}$	Operating temperature	°C	-40 ÷ 125		
MECHANICAL					
a	Acceleration under vibration	m/s^2	50		

CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions	
ON-STATE					
V_{FM}	Peak forward voltage, max	V	2.40	T_j=25 °C; I_{FM}=1570 A	
$V_{F(TO)}$	Forward threshold voltage, max	V	0.80	T_j=$T_{j\,max}$; 0.5 π I_{FAV} < I_T < 1.5 π I_{FAV}	
r_T	Forward slope resistance, max	mΩ	0.800		
BLOCKING					
I_{RRM}	Repetitive peak reverse current, max	mA	100	T_j=$T_{j\,max}$; V_R=V_{RRM}	
THERMAL					
R_{thjc}	Thermal resistance, junction to case				
	per module	°C/W	0.0340	180° half-sine wave, 50 Hz	
	per arm	°C/W	0.0680		
	per module	°C/W	0.0325	DC	
	per arm	°C/W	0.0650		
R_{thch}	Thermal resistance, case to heatsink				
	per module	°C/W	0.0100		
	per arm	°C/W	0.0200		
INSULATION					
V_{ISOL}	Insulation test voltage	kV	3.00	Sine wave, 50 Hz; RMS	t=60 sec
			3.60		t=1 sec
MECHANICAL					
M_1	Mounting torque (M6)[1)]	Nm	6.00	Tolerance ± 15%	
M_2	Terminal connection torque (M10)[1)]	Nm	12.00	Tolerance ± 15%	
w	Weight, max	g	1500		

PART NUMBERING GUIDE

MD	3	-	400	-	52	-	A2	-	N
1	2		3		4		5		6

1. MD - Rectifier Diode
2. Circuit Schematic:
   3 – serial connection
   4 – common Cathode
   5 – common Anode
3. Average Forward Current, A
4. Voltage Code
5. Package Type (M.A2)
6. Ambient Conditions:
   N – Normal

NOTES

[1)] The screws must be lubricated

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